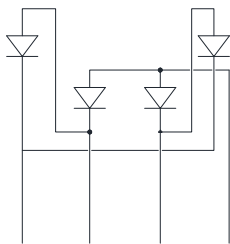




Low VF Bridge Rectifiers

Features

- UL recognition
- 2
- rating, RoHS-compliant
- With heatsink
- **Terminals:** Tin plated leads, solderable per Tc =115
- IO
- A



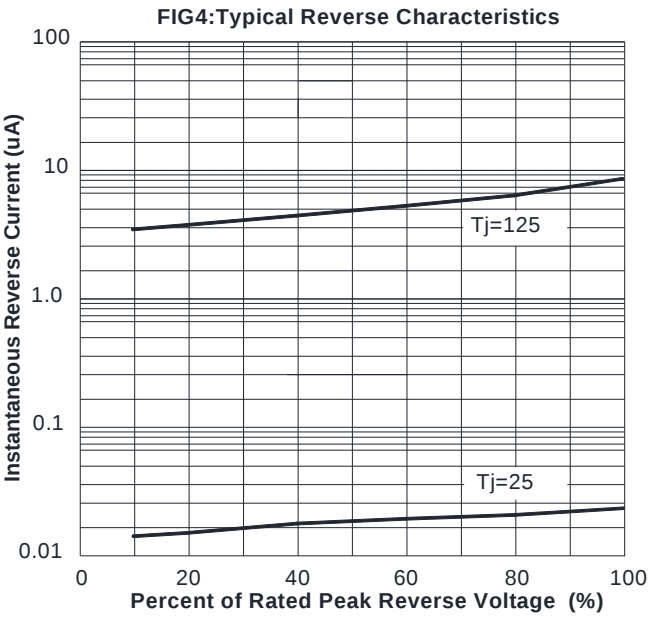
	Without heatsink Ta =25			4.5
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, Tj=25		IFSM	A	360
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25				720
Current squared time @1ms≤t≤8.3ms Tj=25 , Rating of per diode		I²t	A²S	538
Storage temperature		Tstg		-55 ~ +150
Junction temperature		Tj		-55 ~ +150
Dielectric strength @ Terminals to case, AC 1 minute		Vdis	KV	2.5
Mounting torque @Recommend torque 5kg cm		Tor	kg cm	8



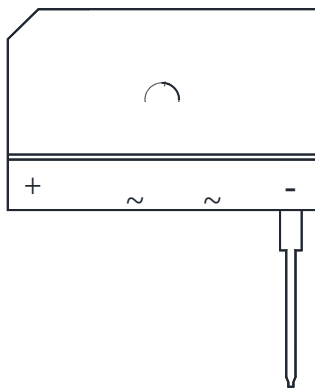
GBJU2506

■Electrical Characteristics $T_a=25$ Unless otherwise specified

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
Instantaneous forward voltage drop per diode	V_F	V	$I_{FM}=12.5A$	0.80	0.875	0.92
DC reverse current at rated DC blocking voltage per diode	I_R	μA	$T_j=25$	-	0.001	5
			$T_j=125$	-	-	50
Junction capacitance	C_j	pF	Measured at 1MHz			



■ Outline Dimensions



Dimensions in millimeters

6KBJ		
Dim	Min	Max
A	29.7	30.3
B	19.7	20.3
C	17.0	18.0
D	4.8	5.8
E	3.8	4.2
F	7.3	7.7
G	9.8	10.2
H	0.9	1.1
I	2.0	2.4
J	2.3	2.7
K	3.4	3.8
L	4.4	4.8
M	10.8	11.2
N	3.1	3.7
O	3.1	3.4
P	0.6	0.8



Disclaimer

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